

### Surface Mount Switching Diodes

 Lead(Pb)-Free

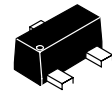
#### Features:

- \* Ultra-Small Surface Mount Package
- \* Fast switching Speed
- \* For General Purpose Switching Applications
- \* High Conductance

#### Mechanical Data:

- \* Polarity: See Diagrams Page.2
- \* Marking: See Diagrams Page.2
- \* Weight: 0.002 grams (approx)

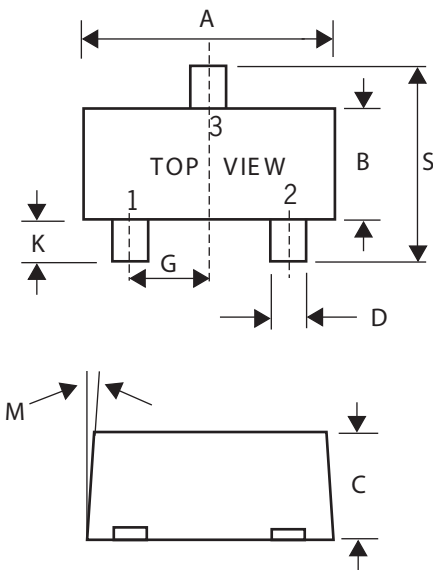
**SWITCHING DIODES**  
**200 mAMPERES**  
**70 VOLTS**



**SOT-523F(SC-89)**

### SOT-523F Outline Dimensions (SC-89)

Unit:mm



| SC-89 |         |      |      |
|-------|---------|------|------|
| Dim   | Min     | Nom  | Max  |
| A     | 1.50    | 1.60 | 1.70 |
| B     | 0.75    | 0.85 | 0.95 |
| C     | 0.60    | 0.70 | 0.80 |
| D     | 0.23    | 0.28 | 0.33 |
| G     | 0.50BSC |      |      |
| J     | 0.10    | 0.15 | 0.20 |
| K     | 0.30    | 0.40 | 0.50 |
| M     | ---     | ---  | 10°  |
| N     | ---     | ---  | 10°  |
| S     | 1.50    | 1.60 | 1.70 |

# BAV70T

## Maximum Ratings (T<sub>A</sub>=25°C Unless otherwise noted)

| Characteristic  | Symbol                            | Value        | Unit        |
|---|-----------------------------------|--------------|-------------|
| Reverse Voltage   | V <sub>R</sub>                    | 70           | V           |
| Forward Continuous Current  | I <sub>O</sub>                    | 200          | mA          |
| Peak Forward Surge Current  | I <sub>FSM</sub>                  | 0.5          | A           |
| Total Device Dissipation FR-5 Board <sup>1</sup><br>T <sub>A</sub> = 25°C<br>Derate above 25°C        | P <sub>d</sub>                    | 225<br>1.8   | mW<br>mW/°C |
| Thermal Resistance  | R <sub>θJA</sub>                  | 555          | °C/W        |
| Total Device Dissipation<br>Alumina Substrate <sup>2</sup> T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>d</sub>                    | 300<br>2.9   | mW          |
| Thermal Resistance  | R <sub>θJA</sub>                  | 345          | °C/W        |
| Junction and Storage Temperature Range  | T <sub>j</sub> , T <sub>STG</sub> | -55 to + 150 | °C          |

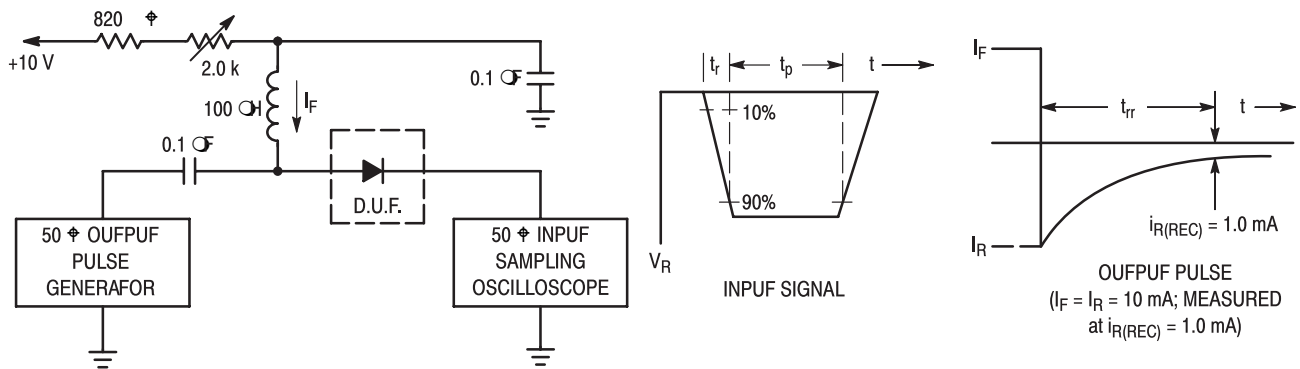
## Electrical Characteristics (T<sub>A</sub>=25°C Unless otherwise noted)

| Characteristic  | Symbol             | Min | Max                        | Unit     |
|---|--------------------|-----|----------------------------|----------|
| Reverse Breakdown Voltage<br>I <sub>R</sub> =100μA  | V <sub>(BR)R</sub> | 70  | -                          | V        |
| Forward Voltage<br>I <sub>F</sub> =1.0mA<br>I <sub>F</sub> =10mA<br>I <sub>F</sub> =50mA<br>I <sub>F</sub> =150mA                     | V <sub>F</sub>     | -   | 715<br>855<br>1000<br>1250 | mV       |
| Total Capacitance<br>V <sub>R</sub> =0V, f=1.0MHz   | C <sub>T</sub>     | -   | 1.5                        | Pf       |
| Reverse Current<br>V <sub>R</sub> =75V<br>V <sub>R</sub> =50V   | I <sub>R</sub>     | -   | 5.0<br>100                 | μA<br>nA |
| Reverse Recover Time<br>I <sub>F</sub> = I <sub>R</sub> = 10 mA, R <sub>L</sub> = 100Ω, I <sub>R(REC)</sub> = 1.0 mA <sup>Fig.1</sup> | T <sub>rr</sub>    | -   | 6.0                        | nS       |
| Forward Recovery Voltage<br>I <sub>F</sub> = 10 mA, t <sub>r</sub> = 20 ns <sup>Fig.2</sup>   | V <sub>RF</sub>    | -   | 1.75                       | V        |

## Device Marking

| Item   | Marking | Equivalent Circuit diagram |
|--------|---------|----------------------------|
| BAV70T | A4      |                            |

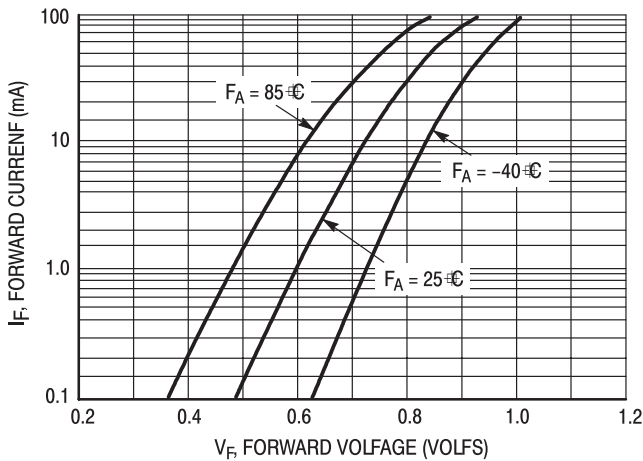
## Electrical Characteristic curves ( $T_A=25^\circ\text{C}$ )



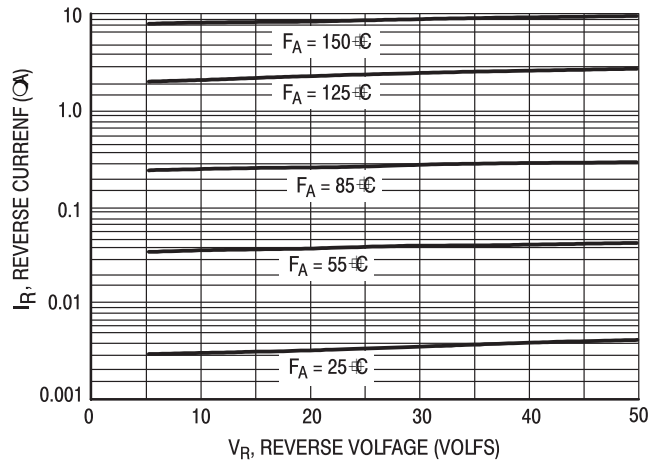
- Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current ( $I_F$ ) of 10 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

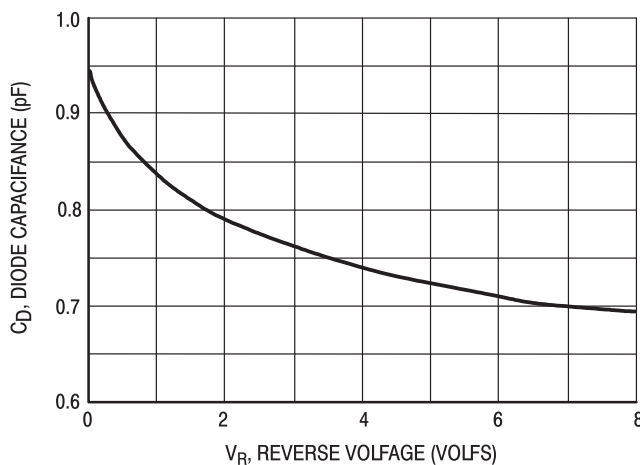
### Curves Applicable to Each Anode



**Figure 2. Forward Voltage**



**Figure 3. Leakage Current**



**Figure 4. Capacitance**